## Product Specification

## PE423641

## Product Description

The PE423641 is a HaRP™ technology-enhanced reflective SP4T RF switch. It has received AEC-Q100 Grade 2 certification and meets the quality and performance standards that makes it suitable for use in harsh automotive environments. It is designed to cover a wide range of wireless applications from 50 MHz through 3 GHz such as cellular antenna band switching, automotive infotainment and traffic safety applications. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE423641 is manufactured on Peregrine's UltraCMOS ${ }^{\circledR}$ process, a patented variation of silicon-oninsulator (SOI) technology on a sapphire substrate, offering excellent RF performance.

Peregrine's HaRPTM technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAS with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram


## UltraCMOS ${ }^{\circledR}$ SP4T RF Switch <br> $50-3000 \mathrm{MHz}$

## Features

- AEC-Q100 Grade 2 certified
- Supports operating temperature up to $+105^{\circ} \mathrm{C}$
- $\mathrm{HaRP}^{T M}$ technology enhancements provide excellent linearity
- Low harmonics of $2 \mathrm{fo}=-83 \mathrm{dBc}$ and $3 \mathrm{fo}=-77 \mathrm{dBc} @+35 \mathrm{dBm}$
- IMD3 of -111 dBm @ WCDMA band 1
- IIP3 of 68 dBm
- Low insertion loss
- 0.50 dB @ 1000 MHz
- 0.65 dB @ 2200 MHz
- High isolation
- 32 dB @ 1000 MHz
- 25 dB @ 2200 MHz
- High ESD performance
- 2 kV HBM on all pins
- 100V MM on all pins
- 1 kV CDM on all pins
- Integrated decoder for 2-pin control
- Accepts 1.8 V and 2.75 V levels

Figure 2. Package Type
16-lead $3 \times 3$ mm QFN


Table 1. Electrical Specifications $@+25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=2.75 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=50 \Omega\right)$

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operational frequency |  |  | 50 |  | 3000 | MHz |
| Insertion loss (symmetric ports) | RFC-RFX | $\begin{aligned} & \hline 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 0.50 \\ & 0.65 \\ & 0.80 \\ & 0.95 \end{aligned}$ | $\begin{aligned} & 0.60 \\ & 0.75 \\ & 0.95 \\ & 1.15 \end{aligned}$ | dB <br> dB <br> dB <br> dB |
| Isolation | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ | $\begin{aligned} & 30 \\ & 23 \\ & 21 \\ & 20 \end{aligned}$ | $\begin{aligned} & 32 \\ & 25 \\ & 23 \\ & 22 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| Return loss (active ports) | RFC-RFX | $\left\lvert\, \begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}\right.$ |  | $\begin{aligned} & 24 \\ & 19 \\ & 16 \\ & 14 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| Return loss (common ports) | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ |  | 23 <br> 16 <br> 14 <br> 13 |  | dB <br> dB <br> dB <br> dB |
| 2nd harmonic | RFX | +35 dBm output power, $850 / 900 \mathrm{MHz}$ <br> +33 dBm output power, 1800/1900 MHz |  | $\begin{aligned} & -83 \\ & -85 \end{aligned}$ | $\begin{aligned} & -80 \\ & -78 \end{aligned}$ | dBc <br> dBc |
| 3rd harmonic | RFX | +35 dBm output power, $850 / 900 \mathrm{MHz}$ +33 dBm output power, $1800 / 1900 \mathrm{MHz}$ |  | $\begin{aligned} & -77 \\ & -78 \end{aligned}$ | $\begin{aligned} & -73.5 \\ & -72.5 \end{aligned}$ | $\mathrm{dBc}$ dBc |
| IMD3 |  | RF Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and -15 dBm CW signal at 1.76 GHz |  | -111 |  | dBm |
| Input IP2 | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 115 |  | dBm |
| Input IP3 | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 68 |  | dBm |
| Input 0.1 dB compression point ${ }^{1}$ | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 37 |  | dBm |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ RF |  | 1 | 2 | $\mu \mathrm{s}$ |

Note 1: Input 0.1 dB compression point is a linearity figure of merit. Refer to Table 3 for the operating RF input power (50 ) .

Table 1A. Electrical Specifications @ -40 to $+105^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=2.75 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=50 \Omega\right)$

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operational frequency |  |  | 50 |  | 3000 | MHz |
| Insertion loss (symmetric ports) | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 0.50 \\ & 0.65 \\ & 0.80 \\ & 0.95 \end{aligned}$ | $\begin{aligned} & 0.75 \\ & 0.90 \\ & 1.10 \\ & 1.30 \end{aligned}$ | dB <br> dB <br> dB <br> dB |
| Isolation | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ | $\begin{aligned} & 30 \\ & 23 \\ & 21 \\ & 20 \end{aligned}$ | $\begin{aligned} & 32 \\ & 25 \\ & 23 \\ & 22 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| Return loss (active ports) | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ |  | 24 <br> 19 <br> 16 <br> 14 |  | dB <br> dB <br> dB <br> dB |
| Return loss (common ports) | RFC-RFX | $\begin{aligned} & 50-1000 \mathrm{MHz} \\ & 1000-2200 \mathrm{MHz} \\ & 2200-2700 \mathrm{MHz} \\ & 2700-3000 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 23 \\ & 16 \\ & 14 \\ & 13 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| 2nd harmonic | RFX | +35 dBm output power, $850 / 900 \mathrm{MHz}$ <br> +33 dBm output power, $1800 / 1900 \mathrm{MHz}$ |  | $\begin{aligned} & -83 \\ & -85 \end{aligned}$ | $\begin{aligned} & -76 \\ & -74 \end{aligned}$ | dBc <br> dBc |
| 3rd harmonic | RFX | +35 dBm output power, $850 / 900 \mathrm{MHz}$ <br> +33 dBm output power, $1800 / 1900 \mathrm{MHz}$ |  | $\begin{aligned} & -77 \\ & -78 \end{aligned}$ | $\begin{aligned} & -69.5 \\ & -68.5 \end{aligned}$ | $\begin{aligned} & \mathrm{dBc} \\ & \mathrm{dBC} \end{aligned}$ |
| IMD3 |  | RF Measured at 2.14 GHz at ANT port, input +20 dBm CW signal at 1.95 GHz and -15 dBm CW signal at 1.76 GHz |  | -111 |  | dBm |
| Input IP2 | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 115 |  | dBm |
| Input IP3 | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 68 |  | dBm |
| Input 0.1 dB compression point ${ }^{1}$ | RFC-RFX | $50-3000 \mathrm{MHz}$ |  | 37 |  | dBm |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ RF |  | 1 | 2 | $\mu \mathrm{s}$ |

Note 1: Input 0.1 dB compression point is a linearity figure of merit. Refer to Table 3 for the operating RF input power (50ת).

Figure 3. Pin Configuration (Top View)


Table 2. Pin Descriptions

| Pin \# | Pin Name | Description |
| :---: | :---: | :--- |
| $1,5,7,9$, <br> $10,12,14$, <br> 16 | N/C | No connect |
| 2 | V $_{\text {DD }}$ | Supply voltage |
| 3 | V2 | Digital control logic input 2 |
| 4 | $\mathrm{~V} 1^{1}$ | Digital control logic input 1 |
| 6 | RF4 $^{1}$ | RF port |
| 8 | RF3 $^{1}$ | RF port |
| 11 | RFC $^{1}$ | RF common |
| 13 | RF1 $^{1}$ | RF port |
| 15 | RF2 $^{1}$ | RF port |
| Pad | GND $^{2}$ | Exposed pad: Ground for proper operation |

Note 1: RF pins $6,8,13$, and 15 must be at 0 VDC. The RF pins do not require DC blocking capacitors for proper operation if the 0 VDC requirement is met.

Table 3. Operating Ranges

| Parameter | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{DD}}$ | 2.65 | 2.75 | 3.3 | V |
| Supply current <br> $\left(\mathrm{V}_{\mathrm{DD}}=2.75 \mathrm{~V},+25^{\circ} \mathrm{C}\right.$ only $)$ | $\mathrm{I}_{\mathrm{DD}}$ |  | 13 | 50 | $\mu \mathrm{~A}$ |
| Digital input high (V1, V2) | $\mathrm{V}_{\mathrm{HH}}$ | 1.4 |  | $\mathrm{~V}_{\mathrm{DD}}$ | V |
| Digital input low (V1, V2) | $\mathrm{V}_{\mathrm{IL}}$ | 0 |  | 0.4 | V |
| RF input power, $\mathrm{CW}^{1}$ | $\mathrm{P}_{\mathrm{MAX}, \mathrm{CW}}$ |  |  | +35 | dBm |
| Operating temperature <br> range | $\mathrm{T}_{\mathrm{OP}}$ | -40 | +25 | +105 | ${ }^{\circ} \mathrm{C}$ |

Note 1: $100 \%$ duty cycle, all bands, $50 \Omega$
Table 4. Absolute Maximum Ratings

| Parameter/Condition | Symbol | Min | Max | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{DD}}$ | -0.3 | 3.7 | V |
| Digital input voltage (V1, V2) | $\mathrm{V}_{\mathrm{I}}$ | -0.3 | 3.7 | V |
| RF input power, max | $\mathrm{P}_{\mathrm{MAX}, \mathrm{ABS}}$ |  | +37 | dBm |
| Storage temperature range | $\mathrm{T}_{\mathrm{ST}}$ | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| ESD voltage $\mathrm{HBM}^{1}$, all pins | $\mathrm{V}_{\mathrm{ESD}, \mathrm{HBM}}$ |  | 2000 | V |
| ESD voltage $\mathrm{MM}^{2}$, all pins | $\mathrm{V}_{\mathrm{ESD}, \mathrm{MM}}$ |  | 100 | V |
| ESD voltage $\mathrm{CDM}^{3}$, all pins | $\mathrm{V}_{\mathrm{ESD}, \mathrm{CDM}}$ |  | 1000 | V |

Notes: 1. Human Body Model (MIL-STD-883 Method 3015)
2. Machine Model (JEDEC JESD22-A115)
3. Charged Device Model (JEDEC JESD22-C101)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

## Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

## Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

## Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE423641 in the 16 -lead $3 \times 3 \mathrm{~mm}$ QFN package is MSL1.

Table 5. Truth Table

| Path | V2 | V1 |
| :---: | :---: | :---: |
| RFC-RF1 | 0 | 0 |
| RFC-RF2 | 1 | 0 |
| RFC-RF3 | 0 | 1 |
| RFC-RF4 | 1 | 1 |

## Switching Frequency

The PE423641 has a maximum 25 kHz switching frequency.
Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reaches $50 \%$ of the final value and the point the output signal reaches within $10 \%$ or $90 \%$ of its target value. Switching time is provided in Table 1 and Table 1A.

Typical Performance Data @ $+\mathbf{2 5}^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=\mathbf{2} . \mathbf{7 5} \mathrm{V}$, unless otherwise specified
Figure 4. Insertion Loss vs Temp (RFC-RFX)


Figure 6. Return Loss vs Temp (Active Port)


Figure 8. Return Loss vs Temp (Common Port)


Typical Performance Data @ $+\mathbf{2 5}^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=\mathbf{2} . \mathbf{7 5} \mathrm{V}$, unless otherwise specified

Figure 10. Isolation vs Temp (RFC-RFX)


Figure 11. Isolation vs $\mathrm{V}_{\mathrm{DD}}$ (RFC-RFX)


## Evaluation Kit

The SP4T switch evaluation board was designed to ease customer evaluation of Peregrine's PE423641. The RF common port is connected through a $50 \Omega$ transmission line via the top SMA connector, J1. RF1, RF2, RF3 and RF4 are connected through $50 \Omega$ transmission lines via SMA connectors $\mathrm{J} 3, \mathrm{~J} 5$, J 2 and J 4 , respectively. A through $50 \Omega$ transmission is available via SMA connectors J6 and J7. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a four metal layer FR4 material with a total thickness of 62 mils. The middle layers provide ground for the transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 32 mils, trace gaps of 25 mils, and metal thickness of 2.1 mils.

Figure 12. Evaluation Board Layouts


Figure 13. Evaluation Board Schematic


Caution: Contains parts and assemblies susceptible to damage by electrostatic discharge (ESD).

Figure 14. Package Drawing
16-lead 3x3 mm QFN


Figure 15. Top Marking Specification


$$
\begin{aligned}
\bullet & =\text { Pin } 1 \text { designator } \\
\text { YYWW } & =\text { Date code, last two digits of the year and work week } \\
\text { ZZZZZZ } & =\text { Last six characters of the assembly lot code }
\end{aligned}
$$

DOC-51207

Figure 16. Tape and Reel Specifications


NTEES:

2. [AMER IN CDFPLINIE HTTH EIA 48I

AS TAE PISITIDN F PICKET, NII PICKET HIE


Device Orientation in Tape

Table 6. Ordering Information

| Order Code | Description | Package | Shipping Method |
| :---: | :---: | :---: | :---: |
| PE423641MLAA-Z | PE423641 SP4T RF switch | Green 16-lead 3 $\times 3 \mathrm{~mm}$ QFN | 3000 units / T\&R |
| EK423641-01 | PE423641 Evaluation kit | Evaluation kit | $1 /$ Box |

## Sales Contact and Information

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